05/12/2017 504365119

PATENT ASSIGNMENT COVER SHEET

Electronic Version v1.1 Stylesheet Version v1.2

EPAS ID: PAT4411811

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date
YASUICHI KONDO	04/18/2003
WATARU HIRASAWA	04/18/2003
NOBOYUKI SUGII	04/24/2003

RECEIVING PARTY DATA

Name:	HITACHI, LTD.	
Street Address:	et Address: 6, KANDA SURUGADAI 4-CHOME, CHIYODA-KU	
City:	: TOKYO	
State/Country:	y: JAPAN	
Name:	RENESAS EASTERN JAPAN SEMICONDUCTOR, INC.	
Name: Street Address:	RENESAS EASTERN JAPAN SEMICONDUCTOR, INC. 3-2, FUJIHASHI 3-CHOME, OME-SHI	
	· ·	

PROPERTY NUMBERS Total: 1

Property Type	Number
Patent Number:	8878244

CORRESPONDENCE DATA

Fax Number: (703)684-1157

Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.

Phone: 7036841120

Email: escotti@mmiplaw.com **Correspondent Name:** MATTINGLY & MALUR, PC Address Line 1: 1800 DIAGONAL ROAD

Address Line 2: **SUITE 210**

Address Line 4: ALEXANDRIA, VIRGINIA 22314

ATTORNEY DOCKET NUMBER: T&A-GENERAL/Z-1704(USMA)P		
NAME OF SUBMITTER:	JOHN R. MATTINGLY	
SIGNATURE:	/John R. Mattingly/	
DATE SIGNED:	05/11/2017	

PATENT REEL: 042356 FRAME: 0270 504365119

Total Attachments: 1

source=(p) Assignment - Inv to HitLtd and RenEas#page1.tif

PATENT REEL: 042356 FRAME: 0271

ASSIGNMENT

(譲渡証)

As a below named inventor, I hereby declare that:

IN CONSIDERATION of the sum of One Dollar (\$1.00) or the equivalent thereof, and other good and valuable consideration paid to me citizen of Japan by Hitachi, Ltd.,

and Renesas Eastern Japan Semiconductor, Inc.,

corporations organized under the laws of Japan,

located at 6, Kanda Surugadai 4-chome, Chiyoda-ku, Tokyo, Japan,

and 3-2, Fujihashi 3-chome, Ome-shi, Tokyo, Japan,

receipt of which is hereby acknowledged I do hereby sell and assign to said Hitachi, Ltd.,

and Renesas Eastern Japan Semiconductor, Inc.,

their successors and assigns, all my right, title and interest, in and for the United States of America, in and to

FABRICATION METHOD OF SEMICONDUCTOR DEVICE AND SEMICONDUCTOR DEVICE

invented by me (if only one is named below) or us (if plural inventors are named below) and described in the application for United States Letters Patent therefor, executed on even date herewith, and all United States Letters Pater which may be granted therefor, and all divisions, continuations and extensions thereof, the said interest being the entire ownership of the said Letters Patent when granted, to be held and enjoyed by said Hitachi, Ltd., and Renesas Eastern Japan Semiconductor, Inc.,

their successors, assigns or other legal representatives, to the full end of term for which said Letters Patent may be granted as fully and entirely as the same would have been held and enjoyed by me or us if this assignment and sale had not been made;

And I hereby agree to sign and execute any further documents or instruments which may be necessary, lawful, and proper in the prosecution of the above-named application or in the preparation and prosecution of any continuing, continuation-in-part, substitute, divisional, renewal, reviewed or reissue applications or in any amendment, extension, or interference proceedings, or otherwise to secure the title thereto in said assignee;

And I do hereby authorize and request the Commissioner of Patents to issue said Letters Patent to said Hitachi, Ltd., and Renesas Eastern Japan Semiconductor, Inc.,

Signed on the date(s) indicated aside our signatures:

INIVENITODIO

	(発明者フルネームサイン)	(署名日)
1)_	Yasuichi Kondo Yasuichi KONDO	18/April/2003
2)_	Wataru Hirasawa Wataru HIRASAWA	18/April/2003
3)_	Nobujuki Sugii Nobuyuki SUGII	24/April/2003
4)_		
5)_		
6)_		
7)_		
8)_		
9)_		
40)		

Data Signed